



## ELF magnetic fields from a photovoltaic system

Prepared by Belgian BioElectroMagnetics Group (BBEMG)

Photovoltaic generators use the [semiconductor properties](#) of the materials they are made of. Photovoltaic solar cells are semiconductors that are able to convert light into electric direct current (DC, meaning [non time-varying current](#)). Current goes through an inverter which converts DC into AC that is used in electric appliances (figure 1). Current generated in excess by the panels and not used in electric appliances is released into the utility grid, if the system is connected to it.

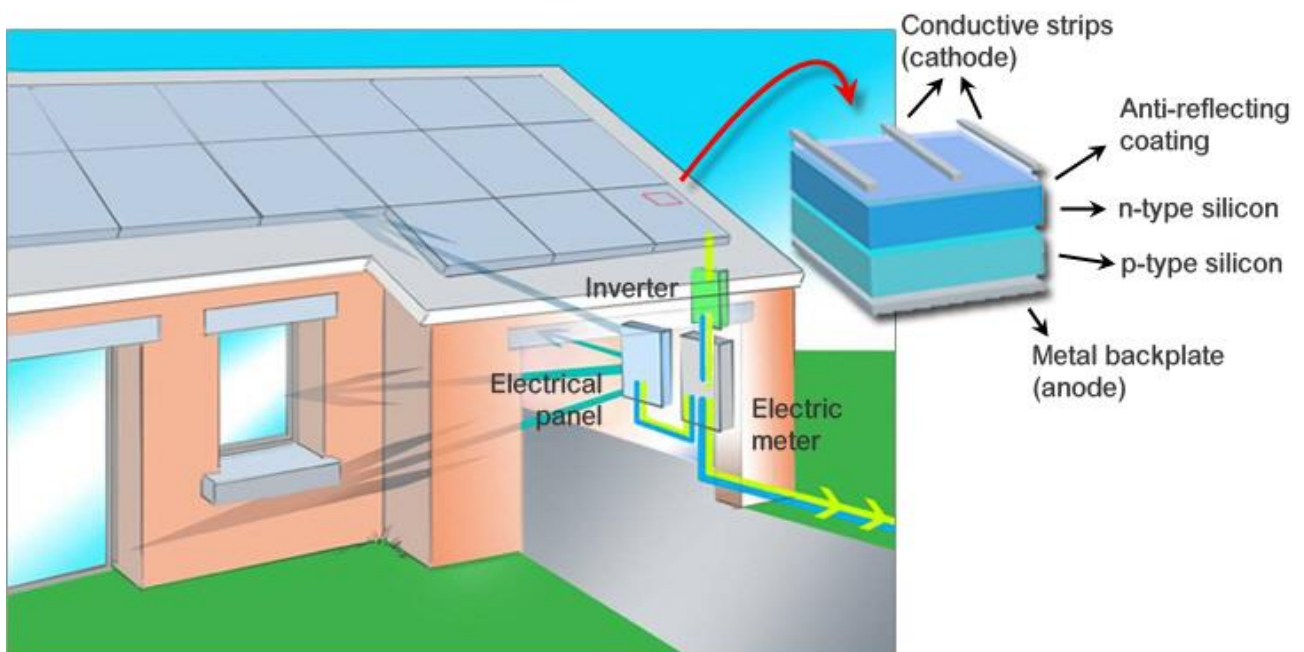


Figure 1

### Magnetic field intensities around a photovoltaic system:

In this example, let us consider 16 collectors assemblies (assembled in series). Its max power is around 5200 W (monocrystalline silicon solar cells, DC 9A).

#### 1. Near the line between the panels and the inverter

An approximate idea of the value of the magnetic induction field can be estimated by the following formula:

$$B \text{ (in Tesla)} = \mu \cdot i / (2 \cdot \pi \cdot r)$$

where

$\mu$  is the permeability of free space (see [Glossary - Magnetic permeability](#))

$i$  (in A) = the current through the panels

$\pi = 3.14$

$r$  = the distance from the line

Thus using the data, it is around **1.8 microTeslas ( $\mu\text{T}$ ) 2m** away from the panels. It is a DC magnetic field. As a comparison, the earth's magnetic field, also constant in time, is around 40  $\mu\text{T}$  at our latitudes (50° north).

## 2. Near the inverter

Here are values measured around an inverter (Table 1).

Table 1 – 50Hz magnetic field values measured at various distances (3 different days)  
(For the “0 cm” measurement, the field probe was placed right next to the inverter, where the measured fields were the highest.)

Distance (in cm)	Day 1: Power around 700 W		Day 2: Power around 2000 W		Day 3: Power around 4000 W	
	50 Hz MF( $\mu\text{T}$ )	Power (W)	50 Hz MF( $\mu\text{T}$ )	Power (W)	50 Hz MF( $\mu\text{T}$ )	Power (W)
0	45	680	165	2400	280	4326
30	0,8	720	2	2075	3,8	4000
60	0,15	730	0,31	2062	0,76	4230
90	0,045	720			0,23	4125

With these measurements, we can state that at around 1 m of the inverter when these panels are delivering their maximum capacity, magnetic field intensities fall below 0.4 $\mu\text{T}$ .

Here is a graph (Figure 2) showing the variations of magnetic field intensities from 10.37 AM to 5.02 PM (probe at 50 cm of the inverter). The highest values occurred in the morning, as the panels are oriented to the East. Fluctuations are related to decreases in electricity production (see ‘red dots’) when clouds were shading the panels.

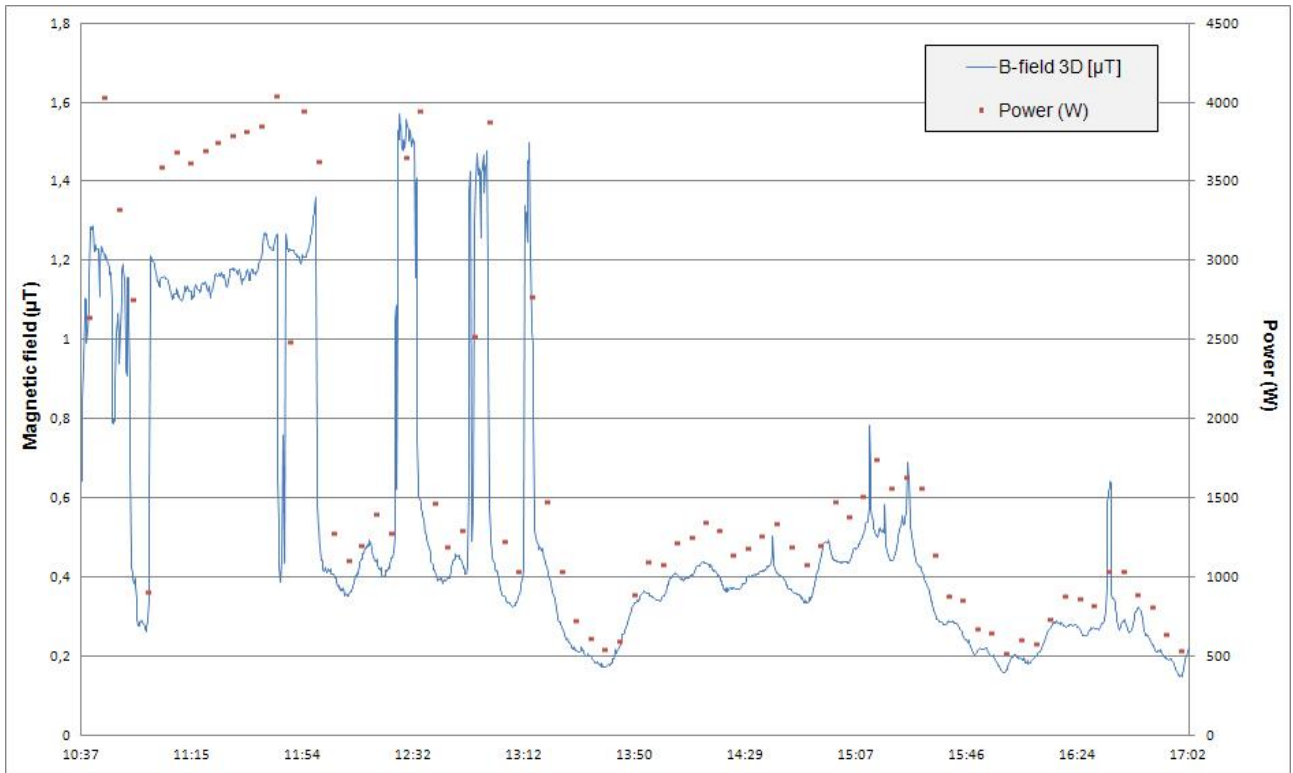


Figure 2 - Variations of magnetic field intensities (B-field in  $\mu\text{T}$ , recording every 16 s.) and power delivered (in W, recording every 5 min.) according to time

### 3. Near the supply line to the electric meter

Inverters are often placed near electrical panels meaning that the length of the supply line inside the home is often very short. With a capacity of around 2000 W, we measured a nearby magnetic field of  $5.5 \mu\text{T}$  (probe by the line), which rapidly falls to  $0.4 \mu\text{T}$  beyond a few tens of cm ( $0.185 \mu\text{T}$  at 30 cm).

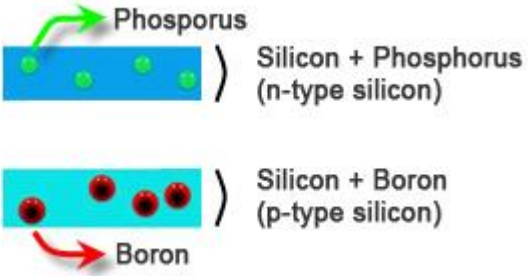
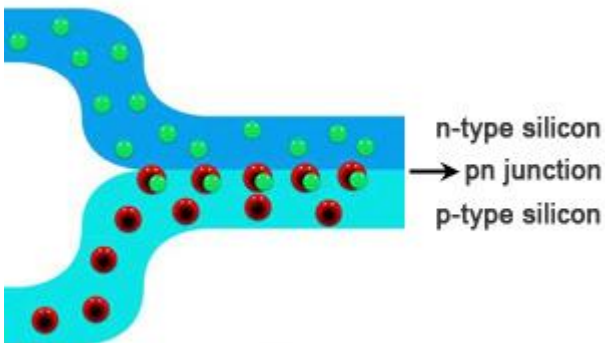
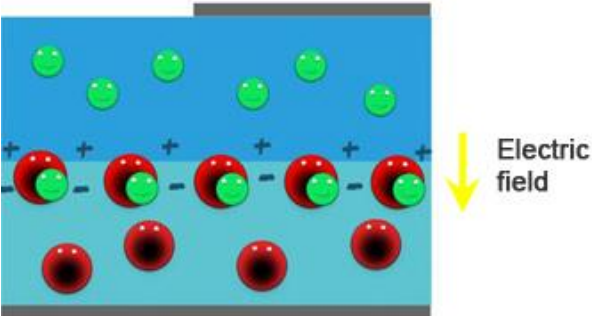
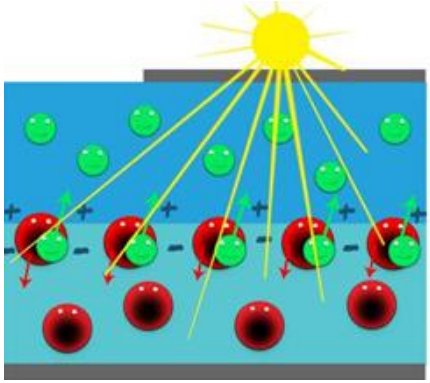
## Want To know more...

### How do panels convert light into DC?

The word “photovoltaic” refers to the energy of the photons of light that is used to produce a voltage.

When photons hit a semiconductor, energy released excites electrons into a higher state of energy. The flow of energized electrons carries electrical energy.

Semiconductor materials such as silicon in their neutral state are not immediately and solely by themselves able to generate an electric current. In fact, they must contain impurities, which is done through a process called “doping”. Here is how it works :

 <p>“Doping” means that elements are introduced into silicon layers to create a globally negative charge with electrons in excess (n-type silicon) or a globally positive charge with holes in excess (p-type silicon).</p>	 <p>When both types of silicon are put in contact, a pn junction is created, that is a space where free charges (electrons and holes) are recombining.</p>
 <p>The recombination of free charges (electrons and holes) generates an intrinsic potential difference (electric field) around the pn junction.</p>	 <p>With the photon's energy, electrons are freed and the electric field forces them to move to the n-type silicon</p>

